



二极管+电晶体+模块

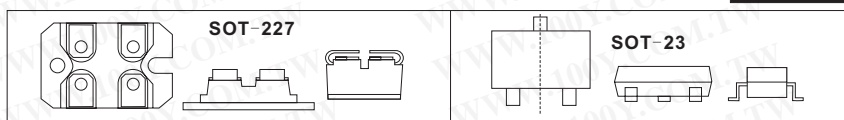
其它系列功率场效电晶体

详细产品规格 - 请点击 cn.100y.com.tw

100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Id(max.) A	Rds(on)(max.) Ω	Pd(max.) W	Vdss(max.) V	N/P Ch.
33101	VNP10N06	ST(SGS)	FULLY AUTOPROTECTED POWER MOSFET	TO-220	15A	300mΩ	42W	70V	
33104	VNP10N07	ST(SGS)	FULLY AUTOPROTECTED POWER MOSFET	TO-220	14A	100mΩ	50W	80V	
33107	VNP20N07	ST(SGS)	FULLY AUTOPROTECTED POWER MOSFET	TO-220	28A	50mΩ	83W	80V	
33110	VNP28N04	ST(SGS)	FULLY AUTOPROTECTED POWER MOSFET	TO-220	49A	35mΩ	83W	42V	
33112	VNP35N07	ST(SGS)	FULLY AUTOPROTECTED POWER MOSFET	TO-220	45A	28mΩ	125W	80V	
33116	VNP49N04	ST(SGS)	FULLY AUTOPROTECTED POWER MOSFET	TO-220	68A	20mΩ	125W	48V	
33099	VNP5N07	ST(SGS)	FULLY AUTOPROTECTED POWER MOSFET	TO-220	7A	200mΩ	31W	80V	
33117	VNW100N04	ST(SGS)	FULLY AUTOPROTECTED POWER MOSFET	3P/TO-247	140A	12mΩ	208W	48V	
32675	VP0610L	VISHAY	P-Channel 60-V (D-S) MOSFET	SOT-23	0.18A	-10V	0.8V	-60V	P Ch.
32677	VQ1000J	VISHAY	N-Channel 60-V (D-S) MOSFET	Dual-In-Line	0.225A	10V	1.3W	60V	N
32451	ZVN2106A	ZETEX	N-CHANNEL ENHANCEMENT	3P/TO-92	450mA	2Ω	700mW	60V	TO-92
32449	ZVN2110A	ZETEX	N-CHANNEL ENHANCEMENT	3P/TO-92	320mA	4Ω	700mW	100V	TO-92
32446	ZVN3306A	ZETEX	N-CHANNEL ENHANCEMENT	3P/TO-92	270mA	5Ω	625mW	60V	TO-92
32442	ZVN4206A	ZETEX	N-CHANNEL ENHANCEMENT	3P/TO-92	600mA	1Ω	0.7W	60V	TO-92
40616	ZXM64N02X	ZETEX	20V N-CHANNEL ENHANCEMENT MODE MOSFET	MSOP8	5.4A	0.040	1.1W	20V	N-Ch.

功率场效模块

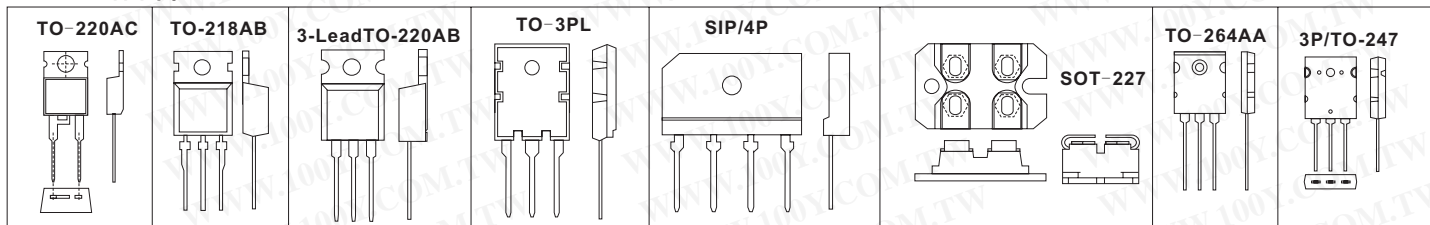
详细产品规格 - 请点击 cn.100y.com.tw



100Y 编号	厂商编号	制造厂商	说明	Id(Cont..) A	Rds(on)Ω	Pd(max.) W	Vdss(max.) V	Package
16557	APT10025JVR	APT	Power MOSFET 模块	34A	0.25Ω	700W	1000V	SOT-227
17626	APT10050JN	APT	Power MOSFET 模块	20.5A	0.50Ω	520W	1000V	SOT-227
42201	MMBF170LT3	ON-Semi.	Power MOSFET	0.5A			60V	SOT-23
42203	MMBF170LT3G	ON-Semi.	Power MOSFET	0.5A			60V	SOT-23
42205	MMBF5457LT1	ON-Semi.	Small Signal JFET	5mA			25V	SOT23
21941	TE53N50E	MOTOROLA	Power MOSFET 模块	53A		400W	500V	

IGBT 晶体/模块 IGBT 晶体

详细产品规格 - 请点击 cn.100y.com.tw



100Y 编号	厂商编号	制造厂商	说明	Vces	Ic(A)	Pd(max)W	Package
35401	10ETF12	IR	FAST SOFT RECOVERY RECTIFIER DIODE	1200V	10A	12KW	TO-220AC
28939	BUP302	SIEMENS	IGBT	1000V	12A	125W	TO-218AB
28940	BUP303	SIEMENS	IGBT	1000V	23A	200W	TO-218AB
28937	BUP304	SIEMENS	IGBT	1000V	35A	310W	TO-218AB
17918	BUP307	SIEMENS	IGBT	1200V	35A	310W	TO-218AB
28938	BUP313	SIEMENS	IGBT	1200V	32A	200W	TO-218AB
20239	BUP314	SIEMENS	IGBT	1200V	52A	300W	TO-3P(TO-218AB)
28943	BUP400	SIEMENS	IGBT	600V	22A	100W	TO-220AB
39314	CT60AM-18F	RENESAS	INSULATED GATE BIPOLAR TRANSISTOR	900V	60A	180W	TO-3PL
39687	D10XB60		Bridge Diode	800V	10A	26W	SIP/4P
33152	GA200SA60S	IR	INSULATED GATE BIPOLAR TRANSISTOR	600V	200A max	630W	SOT-227
33151	GA200SA60U	IR	INSULATED GATE BIPOLAR TRANSISTOR	600V	200A max	630W	SOT-227
33205	GT15Q101	TOSHIBA	N CHANNEL IGBT (HIGH POWER SWITCHING, MOTOR CONTROL APPLICATIONS)	1200V	15.0A	150.0W	TO3
10245	GT60M-301	TOSHIBA	IGBT	900V	60A		3P/TO-264
23946	GT60M303	TOSHIBA	IGBT	900V	60A		TO-3P
33488	HGTG12N60C3D	Intersil	24A, 600V, UFS Series N-Channel IGBT with Anti-Parallel Hyperfast Diode	600V	24A	104W	TO-247
33490	HGTG30N60C3	Intersil	63A, 600V, UFS Series N-Channel IGBT	600V	63.0A	208W	TO-247
33491	HGTG30N60C3D	Intersil	63A, 600V, UFS Series N-Channel IGBT with Anti-Parallel Hyperfast Diodes	600V	63.0A	208W	TO-247
33492	HGTG40N60B3	Intersil	70A, 600V, UFS Series N-Channel IGBT	600V	70A	290W	TO-247
49464	HGTG40N60B3	Fairchild	TO-247	600V	70A	290W	70A, 600V, UFS Series N-Channel IGBT
22284	HGTP3N60C3D	HARRIS	UFS Series N-Channel IGBT with Anti-Parallel Hyperfast Diodes	600V	6A	33W	TO-220AB
33494	HGTP7N60C3D	Fairchild	14A, 600V, UFS Series N-Channel IGBT with Anti-Parallel Hyperfast Diodes	600V	14A	60W	TO-220AB



服务专线: 台湾: 886-3-5753170

传 真: 台湾: 886-3-5753172

E-mail: 台湾: sale@100y.com.tw

深圳: 86-755-83298787

深圳: 86-755-83640655

深圳: 100y@163.com

上海: 86-21-34970699

上海: 86-21-64605107

上海: 100y-1@163.com